

## General purpose transistors (dual digital transistors)

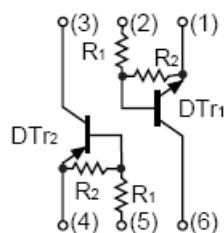
### FEATURES

- Both the DTA143X chip and DTC144E chip in a package
- Mounting possible with SOT-363 automatic mounting machines
- Transistor elements are independent, eliminating interference
- Mounting cost and area be cut in half

### Marking: D5

Equivalent circuit

DT<sub>r1</sub>  
R<sub>1</sub>/R<sub>2</sub>=47kΩ / 47kΩ  
DT<sub>r2</sub>  
R<sub>1</sub>/R<sub>2</sub>=4.7kΩ / 10kΩ



DT<sub>r1</sub>

Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Limits	Unit
Supply voltage	V <sub>CC</sub>	50	V
Input voltage	V <sub>IN</sub>	-10~+40	V
Output current	I <sub>O</sub>	30	mA
	I <sub>C(MAX)</sub>	100	
Power dissipation	P <sub>d</sub>	150	mW
Junction temperature	T <sub>j</sub>	150	°C
Storage temperature	T <sub>STG</sub>	-55~150	°C

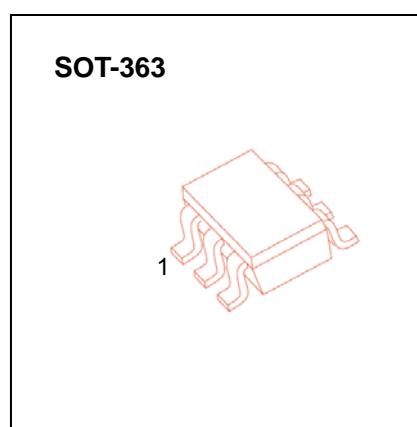
Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Input voltage	V <sub>I(off)</sub>			0.5	V	V <sub>CC</sub> =5V , I <sub>O</sub> =100μA
	V <sub>I(on)</sub>	3				V <sub>O</sub> =0.3V , I <sub>O</sub> =2mA
Output voltage	V <sub>O(on)</sub>			0.3	V	I <sub>O</sub> /I <sub>I</sub> =10mA/0.5mA
Input current	I <sub>I</sub>			0.18	mA	V <sub>I</sub> =5V
Output current	I <sub>O(off)</sub>			0.5	μA	V <sub>CC</sub> =50V, V <sub>I</sub> =0
DC current gain	G <sub>I</sub>	68				V <sub>O</sub> =5V , I <sub>O</sub> =5mA
Input resistance	R <sub>1</sub>	32.9		61.1	KΩ	
Resistance ratio	R <sub>2</sub> /R <sub>1</sub>	0.8	1	1.2		
Transition frequency	f <sub>T</sub>		250		MHz	V <sub>O</sub> =10V , I <sub>O</sub> =5mA,f=100MHz

DT<sub>r2</sub>

Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Limits	Unit
Supply voltage	V <sub>CC</sub>	-50	V
Input voltage	V <sub>IN</sub>	-20~+7	V
Output current	I <sub>O</sub>	-100	mA
	I <sub>C(MAX)</sub>	-100	
Power dissipation	P <sub>d</sub>	150	mW
Junction temperature	T <sub>j</sub>	150	°C
Storage temperature	T <sub>STG</sub>	-55~150	°C



**Electrical characteristics (Ta=25°C)**

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
<b>Input voltage</b>	V <sub>I(off)</sub>			-0.3	V	V <sub>CC</sub> =-5V ,I <sub>O</sub> =-100μA
	V <sub>I(on)</sub>	-2.5				V <sub>O</sub> =-0.3V ,I <sub>O</sub> =-20mA
<b>Output voltage</b>	V <sub>O(on)</sub>			-0.3	V	I <sub>O</sub> /I <sub>I</sub> =-10mA/-0.5mA
<b>Input current</b>	I <sub>I</sub>			-1.8	mA	V <sub>I</sub> =-5V
<b>Output current</b>	I <sub>O(off)</sub>			-0.5	μA	V <sub>CC</sub> =-50V, V <sub>I</sub> =0
<b>DC current gain</b>	G <sub>I</sub>	30				V <sub>O</sub> =-5V ,I <sub>O</sub> =-10mA
<b>Input resistance</b>	R <sub>1</sub>	3.29		6.11	KΩ	
<b>Resistance ratio</b>	R <sub>2</sub> /R <sub>1</sub>	1.7		2.6		
<b>Transition frequency</b>	f <sub>T</sub>		250		MHz	V <sub>O</sub> =-10V ,I <sub>O</sub> =-5mA,f=100MHz